

IN THE CLAIMS:

Please substitute the following claims for the same-numbered claims in the application:

1. (Currently Amended) A simulator comprising:

a memory for storing a computer model of an integrated circuit comprising a device that ~~is one of a transistor, a capacitor and a resistor~~ comprises an integrated circuit component and that has at least one performance attribute, wherein said computer model is generated based on a target model for said device ~~transistor~~ and wherein said target model is created using a target performance parameter range for said performance attribute and is adapted to predict process and design variations of said device; and

a processor in communication with said memory ~~device~~ and adapted to determine said target performance parameter range and to execute said computer model,

wherein said target performance parameter range comprises ~~includes a~~ multiple first bounded ranges and a second bounded range,

wherein each of said first bounded ranges comprises a range of performance parameter variations ~~within a single manufacturing process due to manufacturing process variations and is based on a corresponding one of multiple model curves for different designs of a single design~~ for said device that achieve a same performance point,

wherein each of said multiple different designs is directed to a variation of a single design for said integrated circuit, and

wherein said second bounded range is constrained by at least two of said multiple model curves so as to comprise[[s]] performance parameter variations between said multiple different designs for said device.

2. (Currently Amended) The simulator in claim 1, ~~wherein said multiple designs are directed to variations of a single design~~ wherein said second bounded range is constrained by a most linear of said multiple model curves and a least linear of said multiple model curves and wherein said target performance parameter range is constrained by an upper edge of a first bounded range around said most linear of said multiple model curves and a lower edge of another first bounded range around said least linear of said multiple model curves.

3. (Currently Amended) The simulator in claim 1, wherein said target performance parameter range is the same for a target model of said device and a final hardware design of said device.

4. (Cancelled).

5. (Currently Amended) The simulator in claim[[4]], wherein said target performance parameter range is bounded by ~~both of~~ said multiple first bounded ranges and said second bounded range.

6. (Currently Amended) The simulator in claim 4, wherein said multiple different designs of said device are permitted to vary as long as ~~said target performance parameters are~~ is maintained within said target performance parameter range ~~at least one of said first bounded range and said second bounded range~~.

7. (Currently Amended) The simulator in claim 1, wherein said target performance parameter range comprises a plurality of performance points.

8. (Currently Amended) The simulator in claim 1, wherein said target performance parameter range comprises at least a two-dimensional range of a plurality of performance points.

9. (Currently Amended) A computer-implemented method for designing a product having a device comprising an integrated circuit component, ~~wherein said device is one of a transistor, a capacitor and a resistor and a~~ wherein said product is tolerant to variance in a given target performance parameter for a given performance attribute of said device, said method comprising:

designing said product using a computer model that is based on a target model of said device, wherein said target model is created using ~~said~~ a target performance parameter range for said performance attribute,

wherein said target performance parameter range comprises ~~includes a multiple~~ first bounded ranges and a second bounded range,

wherein each of said first bounded ranges comprises a range of performance parameter variations ~~within a single manufacturing process~~ due to manufacturing process variations and is

based on a corresponding one of multiple model curves for different designs of single design for
said device that achieve a same performance point,

wherein each of said multiple different designs is directed to a variation of a single design
for said device, and

wherein said second bounded range is constrained by at least two of said multiple model
curves so as to comprise[[s]] performance parameter variations between said multiple different
designs for said device.

10. (Currently Amended) The method of claim 9, ~~wherein said multiple designs are directed~~
~~to variations of said single design~~ wherein said second bounded range is constrained by a most
linear of said multiple model curves and a least linear of said multiple model curves and wherein
said target performance parameter range is constrained by an upper edge of a first bounded range
around said most linear of said multiple model curves and a lower edge of another first bounded
range around said least linear of said multiple model curves.

11. (Currently Amended) The method of claim 9, wherein said target performance parameter
range is the same for a target model of said device and a final hardware design of said device.

12. (Cancelled).

13. (Currently Amended) The method in claim 9, wherein said multiple different designs of said device are permitted to vary within said model as long as said given target performance parameter remains within said target performance parameter range ~~first bounded range and said second bounded range~~.

14. (Currently Amended) A method of developing a product ~~having~~ comprising a device with at least one performance attribute, wherein said device comprises an integrated circuit component ~~is one of a transistor, a capacitor and a resistor~~, said method comprising:

developing device goals for said device, wherein said device goals are based on product goals;

developing a target performance parameter range for said performance attribute based on said device goals,

wherein said target performance parameter range comprises ~~includes a multiple~~ first bounded ranges and a second bounded range,

wherein each of said first bounded ranges comprises a range of performance parameter variations ~~within a single manufacturing process~~ due to manufacturing process variations and is based on a corresponding one of multiple model curves for different designs of single design for said device that achieve a same performance point,

wherein each of said multiple different designs is direct to a variation of a single design for said device, and

wherein said second bounded range is constrained by at least two of said multiple model curves so as to comprise[[s]] performance parameter variations between said multiple different designs for said device;

producing a target model of said device based on said device goals and said target performance parameter range, wherein said target model is adapted to predict process and design variations of said device; and

designing said product with said device based on said target model.

15. (Currently Amended) The method of claim 14, wherein said target performance parameter range comprises a plurality of performance points.

16. (Currently Amended) The method of claim ~~[[15]]~~ 14, ~~wherein said multiple designs are directed to variations of a single design~~ wherein said second bounded range is constrained by a most linear of said multiple model curves and a least linear of said multiple model curves and wherein said target performance parameter range is constrained by an upper edge of a first bounded range around said most linear of said multiple model curves and a lower edge of another first bounded range around said least linear of said multiple model curves.

17. (Currently Amended) The method of claim 14, wherein said target performance parameter range is the same for said target model of said device and a final hardware design of said device.

18. (Currently Amended) The method in claim 14, wherein said multiple different designs are permitted to vary as long as said target performance parameters are maintained ~~remains~~ within said ~~first bounded range and said second bounded~~ target performance parameter range.

19. (Currently Amended) A method of designing a device with at least one performance attribute, wherein said device comprises an integrated circuit component ~~is one of a transistor, a capacitor and a resistor~~, said method comprising:

providing a target model for said device;

wherein said target model is created based on a target performance parameter range for said performance attribute,

wherein said target performance parameter range comprises ~~includes a~~ multiple first bounded ranges and a second bounded range,

wherein each of said first bounded ranges comprise[[s]] a range of performance parameter variations within a single manufacturing process due to manufacturing process variations and is based on a corresponding one of multiple model curves for different designs of single design for said device that achieve a same performance point,

wherein each of said multiple different designs is direct to a variation of a single design for said device, and

wherein said second bounded range is constrained by at least two of said multiple model curves so as to comprise[[s]] performance parameter variations between said multiple different designs for said device;

developing a design for said device based on said target model;

proposing a modification of said design, wherein said modification comprises one of adding a particular feature into said design and modifying said particular feature already in said design;

determining primary parameters for said particular feature;

determining secondary parameters from said primary parameters; and

balancing design choices related to said modification and, particularly, to said primary parameters and said secondary parameters in order to maintain device performance within said ~~first bounded range and said second bounded range~~ of said target performance parameter range.

20. (Original) The method of claim 19, wherein said step of determining secondary parameters further comprises the steps of:

determining at least one further secondary parameter from said secondary parameters;

and

correlating said secondary parameters to said at least one further secondary parameter.

21. (Original) The method of claim 19, further comprising the step of verifying that all primary and secondary parameters are within allowable limits.

22. (Original) The method of claim 19, wherein said primary parameters comprise first-order primary parameters and second-order primary parameters.

23. (Cancelled).

24. (Currently Amended) A method of developing a product ~~having comprising~~ a device with at least one performance attribute, wherein said device comprises an integrated circuit component ~~is one of a transistor, a capacitor and a resistor,~~ said method comprising:

developing device goals for said device, wherein said device goals are based on product goals for said product;

developing a target performance parameter range for said performance attribute based on said device goals,

wherein said target performance parameter range comprises includes a multiple first bounded ranges and a second bounded range,

wherein each of said first bounded ranges comprises a range of performance parameter variations ~~within a single manufacturing process due to manufacturing process~~ variations and is based on a corresponding one of multiple model curves for different designs of single design for said device that achieve a same performance point,

wherein each of said multiple different designs is direct to a variation of a single design for said device, and

wherein said second bounded range is constrained at least two of said multiple model curves so as to comprise[[s]] performance parameter variations between said multiple different designs for said device;

producing a target model of said device based on said device goals and said target performance parameter range, wherein said target model is adapted to predict process and design variations of said device;

creating a computer model of said product, wherein said computer model of said product is based on said target model; and

simulating said computer model of said product to determine whether said product goals have been met.

25. (Previously Presented) The method of claim 24, further comprising:
altering a device design to produce an altered device design; and
accepting said altered device design only if said altered device design performs within said target performance parameter range ~~first bounded range and said second bounded range~~.

26. (Original) The method of claim 25, further comprising:
refining said target model based on said altered device design; and
designing at least said product based on said refined target model.

27. (Original) The method of claim 25, wherein said step of accepting said altered device design further comprises the steps of carrying out experiments on test chips.

28. (Original) The method of claim 24, wherein said step of designing said product further comprises:

providing design goals for said product; and
developing a product model from said target model and from said design goals for said product.

29. (Original) The method of claim 28, further comprising:
simulating said product model;
determining whether said design goals for said product have been met; and
altering said design of said product if said product design goals have been met.
30. (Previously Presented) The method of claim 24, wherein said accepting process comprises:
calculating a primary parameter from a physical device feature;
calculating a secondary parameter based on said primary parameter; and
comparing said secondary parameter to said target performance parameter.
31. (Original) The method of claim 30, further comprising correlating other secondary parameters from correlations to said secondary parameters.
32. (Original) The method of claim 30, wherein said primary parameter is directly related to said physical device feature.
33. (Previously Presented) The method of claim 30, wherein said calculating of said secondary parameter is performed using predetermined primary-to-secondary correlation calculations.

34. (Currently Amended) The method of claim 24, wherein said target performance parameters are the same for a target model of said device and a final hardware design of said device.

35. (Currently Amended) The method of claim 24, wherein device design is permitted to vary as long as said target performance parameters are maintained within said target performance parameter range.

36. (Currently Amended) A program storage device readable by computer and tangibly embodying a model of an integrated circuit device that has at least one performance attribute, ~~that is one of a transistor, a capacitor and a resistor, and that is executable by said computer~~, said model, executable by said computer, comprising:

a set of subroutines created using a target performance parameter range for said performance attribute, wherein said set of subroutines, when executed by said computer, predict process and design variations of said device,

wherein said target performance parameter range comprises ~~includes a~~ multiple first bounded ranges and a second bounded range,

wherein each of said first bounded range comprises a range of performance parameter variations ~~within a single manufacturing process~~ due to manufacturing process variations and is based on a corresponding one of multiple model curves for different designs of single design for said device that achieve a same performance point,

wherein each of said multiple different designs is direct to a variation of a single design for said device, and

wherein said second bounded range is constrained by at least two of said multiple model curves so as to comprise[[s]] performance parameter variations between said multiple different designs for said device.

37. (Currently Amended) The program storage device in claim 36, ~~wherein said performance parameter is constrained within at least one of said first bounded range and said second bounded range~~ wherein said second bounded range is constrained by a most linear of said multiple model curves and a least linear of said multiple model curves and wherein said target performance parameter range is constrained by an upper edge of a first bounded range around said most linear of said multiple model curves and a lower edge of another first bounded range around said least linear of said multiple model curves.

38. (Previously Presented) The program storage device in claim 36, wherein said performance parameter comprises a plurality of performance points.

39. (Previously Presented) The program storage device, wherein said performance parameter comprises at least a two-dimensional range of a plurality of performance points.

40. (Currently Amended) A program storage device readable by computer and tangibly embodying a program of instructions executable by said computer to perform an integrated circuit development method, said method comprising:

producing a target model of a device for a product using a target performance parameter range for a performance attribute of said integrated circuit device, wherein said device comprises an integrated circuit component ~~is one of a transistor, a capacitor and a resistor,~~ and wherein said target model comprises a set of subroutines that are adapted to predict process and design variations of said device,

wherein said target performance parameter range includes [[a]] multiple first bounded ranges and a second bounded range,

wherein each of said first bounded range comprises a range of performance parameter variations ~~within a single manufacturing process~~ due to manufacturing process variations and is based on a corresponding one of multiple model curves for different designs of single design for said device that achieve a same performance point,

wherein each of said multiple different designs is direct to a variation of a single design for said device, and

wherein said second bounded range is constrained by at least two of said multiple model curves so as to comprise [[s]] performance parameter variations between said multiple different designs for said device; and

creating a computer model of said product, wherein said computer model of said product is based on said target model.

41. (New) The method of claim 19, wherein said second bounded range is constrained by a most linear of said multiple model curves and a least linear of said multiple model curves and wherein said target performance parameter range is constrained by an upper edge of a first bounded range around said most linear of said multiple model curves and a lower edge of another first bounded range around said least linear of said multiple model curves.

42. (New) A computer-implemented method of developing a product comprising a device with at least one performance attribute, wherein said device comprises an integrated circuit component, said method comprising:

designing said product using a computer model that is based on a target model of said device, wherein said target model is created using said a target performance parameter range for said performance attribute,

wherein said target performance parameter range comprises multiple first bounded ranges and a second bounded range,

wherein each of said first bounded ranges comprises a range of performance parameter variations due to manufacturing process variations and is based on a corresponding one of multiple model curves for different designs of said device that achieve a same performance point,

wherein each of said multiple different designs is directed to a variation of a single design for said device,

wherein said second bounded range is constrained is constrained by a most linear of said multiple model curves and a least linear of said multiple model curves, and

wherein target performance parameter range is constrained by an upper edge of a first bounded range around said most linear of said multiple model curves and a lower edge of another first bounded range around said least linear of said multiple model curves.